

isc N-Channel MOSFET Transistor

IXTP100N04T2

FEATURES

- Static drain-source on-resistance: $R_{DS}(on) \leq 7m\Omega@V_{GS}{=}10V$
- Fully characterized avalanche voltage and current
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



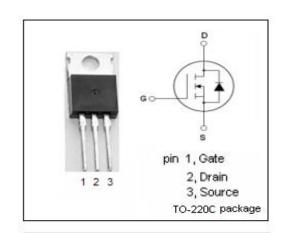
- · Current Regulators
- · Solid State Circuit Breakers

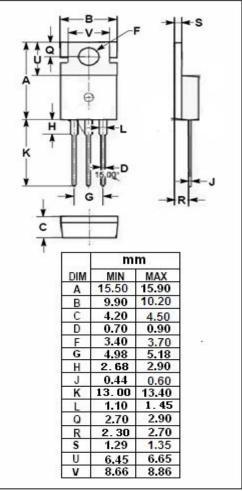
• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{DSS}	Drain-Source Voltage	40	V	
V _{GS}	Gate-Source Voltage	±20 V		
I _D	Drain Current-Continuous 100		А	
I _{DM}	Drain Current-Single Pulsed 300		А	
P _D	Total Dissipation @T _C =25°C 150		W	
Tj	Operating Junction Temperature	-55~175	°C	
T _{stg}	Storage Temperature	-55~175	$^{\circ}$	

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R _{th(j-c)}	Junction-to-case thermal resistance	1.0	°C/W







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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; ID = 250 μ A	40		V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} ; ID = 250 μ A	2.0	4.0	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} =10V; I _D = 25A		7	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±20V;V _{DS} =0V		±100	nA
I _{DSS}	Drain-Source Leakage Current	V _{DS} = V _{DSS} ; V _{GS} = 0V		2	- μ Α
		V _{DS} = V _{DSS} ; V _{GS} = 0V;T _J = 150°C		50	
V _{SD}	Diode forward voltage	I _F = 50A; V _{GS} = 0V		1.2	V



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